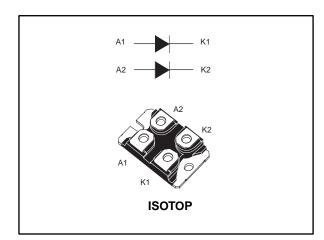


STPS160H100TV

High voltage power Schottky rectifier

Datasheet - production data



Features

- Negligible switching losses
- High junction temperature capability
- Low leakage current
- Good trade-off between leakage current and forward voltage drop
- Avalanche rated
- Low induction package
- Insulated package ISOTOP:
 - Insulated voltage: 2500 V_{RMS}
 - Capacitance: 45 pF

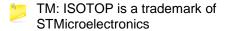
Description

High frequency dual Schottky rectifier designed for high frequency telecom, computer SMPS and other power converters.

Packaged in ISOTOP, this device is intended for use in medium voltage operation and in high frequency circuitries where low switching losses and low noise are required.

Table 1: Device summary

| Symbol | Value |
|-----------------------|----------|
| I _{F(AV)} | 2 x 80 A |
| V _{RRM} | 100 V |
| T _j (max.) | 150 °C |
| V _F (max.) | 0.68 V |



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1 Characteristics

Table 2: Absolute ratings (limiting values, per diode)

| Symbol | Parameter | Value | Unit | | |
|---------------------|---|----------------------------|--------------|-------------|----|
| V _{RRM} | Repetitive peak reverse voltage | | | 100 | V |
| I _{F(RMS)} | Forward rms current | | | 180 | Α |
| I _{F(AV)} | Average forward current, δ = 0.5 T_C = 110 °C $Per diode$ Per device | | 80 160 | Α | |
| I _{FSM} | Surge non repetitive forward current | $t_p = 10 \text{ ms sin}$ | usoidal | 1000 | Α |
| I _{RRM} | Repetitive peak reverse current | t _p = 2 μs squa | re f = 1 kHz | 2 | Α |
| I _{RSM} | Non repetitive peak reverse current t_p = 100 μ s square | | 10 | Α | |
| Parm | Repetitive peak avalanche power t_p = 10 μ s T_j = 125 °C | | 5400 | W | |
| T _{stg} | Storage temperature range | | | -55 to +150 | °C |
| Tj | Maximum operating junction temperature ⁽¹⁾ | | | 150 | °C |

Notes:

Table 3: Thermal parameters

| Symbol | Parameter Maximum values | | | |
|----------------------|--------------------------|-----------|------|------|
| D | lunction to cons | Per diode | 0.9 | |
| R _{th(j-c)} | Junction to case | Total | 0.5 | °C/W |
| R _{th(c)} | Coupling | | 0.14 | |

When the diodes 1 and 2 are used simultaneously:

 $\Delta T_{j} \left(diode1 \right) = P_{\left(diode1 \right)} \, x \, \, R_{th\left(j\text{-}c \right)} \left(per \, diode \right) \, + \, P_{\left(diode2 \right)} \, x \, \, R_{th\left(c \right)}$

 $^{^{(1)}(}dP_{tot}/dT_j) < (1/R_{th(j\text{-}a)}) \ condition \ to \ avoid \ thermal \ runaway \ for \ a \ diode \ on \ its \ own \ heatsink.$

STPS160H100TV Characteristics

Table 4: Static electrical characteristics

| Symbol | Parameter | Test conditions | | Min. | Тур. | Max. | Unit |
|-------------------------------|--|-------------------------|---------------------------------------|------|------|------|------|
| I _R ⁽¹⁾ | Davis and Indiana are summer. | T _j = 25 °C | \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ | - | | 40 | μΑ |
| IR'' | Reverse leakage current | T _j = 125 °C | $V_R = V_{RRM}$ | ı | 13 | 50 | mA |
| | V _F ⁽²⁾ Forward voltage drop | T _j = 25 °C | I _F = 60 A | ı | | 0.75 | |
| | | T _j = 125 °C | | ı | 0.59 | 0.63 | |
| | | T _j = 25 °C | I _F = 80 A | ı | | 0.80 | |
| V ₋ (2) | | T _j = 125 °C | | ı | 0.63 | 0.68 | V |
| VF(=) | | T _j = 25 °C | I _F = 120 A | ı | | 0.87 | V |
| | | T _j = 125 °C | | ı | 0.69 | 0.74 | |
| | | T _j = 25 °C | I _F = 160 A | - | | 0.92 | |
| | | T _j = 125 °C | | - | 0.75 | 0.80 | |

Notes:

To evaluate the maximum conduction losses, use the following equation:

$$P = 0.56 \text{ x } I_{F(AV)} + 0.0015 \text{ x } I_{F^2(RMS)}$$

 $^{^{(1)}}$ Pulse test: t_p = 5 ms, δ < 2%

 $^{^{(2)}\}text{Pulse}$ test: t_p = 380 $\mu\text{s},\,\delta$ < 2%

Characteristics STPS160H100TV

1.1 Characteristics (curves)

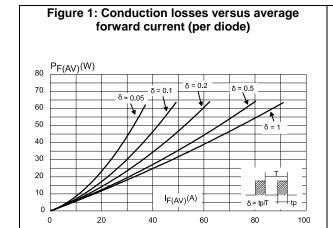


Figure 2: Forward voltage drop versus forward current (δ = 0.5, per diode)

100
R_{th(j-a)} = R_{th(j-c)}

80
R_{th(j-a)} = R_{th(j-c)}

100
R_{th(j-a)} = R_{th(j-c)}

100
125
150

versus pulse duration

PARM(tp)
PARM(10 µs)

0.1

10

0.001

Figure 3: Normalized avalanche power derating

Figure 4: Relative variation of thermal impedance junction versus pulse duration (per diode)

1.0

2th(j-c)/Rth(j-c)

0.8

0.6

0.4

0.2

0.2

0.2

0.3

1E-3

1E-2

1E-1

1E+0

5E+0

voltage applied (typical values, per diode)

5E+1

1E+1

1E+0

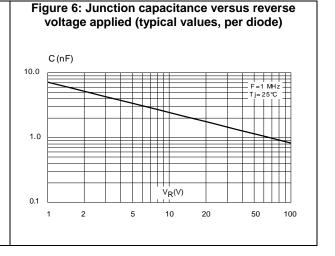
1E-1

1E-2

1E-3

0 10 20 30 40 50 60 70 80 90 100

Figure 5: Reverse leakage current versus reverse



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tp(µs)

1000

100

Downloaded from Arrow.com.

STPS160H100TV Characteristics

Figure 7: Forward voltage drop versus forward current (maximum values, per diode)

Package information STPS160H100TV

2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
 Recommended torque value: 1.3 N·m
- Maximum torque value: 1.5 N⋅m

STMicroelectronics strongly recommends the use of the screws delivered with this product.

The use of any other screws is entirely at the user's own risk and will invalidate the warranty.



STPS160H100TV Package information

2.1 ISOTOP package information

Figure 8: ISOTOP package outline

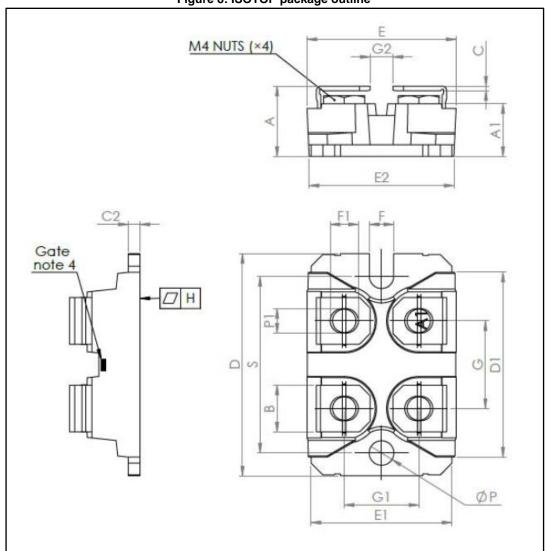


Table 5: ISOTOP package mechanical data

| | Dimensions | | | |
|--------|------------------|-------|--------|-------|
| Ref. | Ref. Millimeters | | Inch | ies |
| | Min. | Max. | Min. | Max. |
| Α | 11.80 | 12.20 | 0.460 | 0.480 |
| A1 | 8.90 | 9.10 | 0.350 | 0.358 |
| В | 7.80 | 8.20 | 0.307 | 0.323 |
| С | 0.75 | 0.85 | 0.030 | 0.033 |
| C2 | 1.95 | 2.05 | 0.077 | 0.081 |
| D | 37.80 | 38.20 | 1.488 | 1.504 |
| D1 | 31.50 | 31.70 | 1.240 | 1.248 |
| E | 25.15 | 25.50 | 0.990 | 1.004 |
| E1 | 23.85 | 24.15 | 0.939 | 0.951 |
| E2 | 24.80 | | 0.976 | |
| G | 14.90 | 15.10 | 0.587 | 0.594 |
| G1 | 12.60 | 12.80 | 0.496 | 0.504 |
| G2 | 3.50 | 4.30 | 0.138 | 0.169 |
| F | 4.10 | 4.30 | 0.161 | 0.169 |
| F1 | 4.60 | 5 | 0.181 | 0.197 |
| Н | -0.05 | 0.1 | -0.002 | 0.004 |
| Diam P | 4 | 4.30 | 0.157 | 0.169 |
| P1 | 4 | 4.40 | 0.157 | 0.173 |
| S | 30.10 | 30.30 | 1.185 | 1.193 |

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3 Ordering information

Table 6: Ordering information

| Order code | Marking | Package | Weight | Base qty. | Delivery mode |
|---------------|---------------|---------|--------------------------|------------------|------------------|
| STPS160H100TV | STPS160H100TV | ISOTOP | 27 g (without screws) | 10 (with screws) | Tube |

4 Revision history

Table 7: Document revision history

| | | <u>-</u> | | |
|-------------|----------|--|--|--|
| Date | Revision | Changes | | |
| Jul-2003 | 3a | Last release. | | |
| 06-Jun-2017 | 4 | Updated Section 2.1: "ISOTOP package information". | | |
| 24-Nov-2017 | 5 | Updated Table 5: "ISOTOP package mechanical data". | | |

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